

	<b>Hits</b>	<b>Search Text</b>
<b>1</b>	0	OLED and ((n+m) with subframes)
<b>2</b>	28	OLED and (subframes)
<b>3</b>	51	OLED and (plurality near5 frames)
<b>4</b>	0	OLED and (subframes)
<b>5</b>	0	OLED and (plurality near5 frames)
<b>6</b>	4	OLED and (subframes)
<b>7</b>	11	OLED and (plurality near5 frames)
<b>8</b>	14	OLED and (plurality with frames)
<b>9</b>	0	(pseudo adj4 contours) and (plurality adj3 frames)
<b>10</b>	3	(pseudo adj4 contours) and subframes
<b>11</b>	6	(pseudo adj4 contours) and subframes
<b>12</b>	9	(pseudo adj4 contours) and subframes
<b>13</b>	21	(pseudo adj4 contours) and subfields
<b>14</b>	18	((pseudo adj4 contours) and subfields) not ((pseudo adj4 contours) and subframes)
<b>15</b>	0	(pseudo adj4 contours) and subfields and OLED
<b>16</b>	0	(pseudo adj4 contours) and subfields and OLED
<b>17</b>	30	(pseudo adj4 contours) and subfields
<b>18</b>	4	(pseudo adj4 contours) and subfields and LED
<b>19</b>	0	OLED and (three adj5 TFT)
<b>20</b>	75	OLED and TFT
<b>21</b>	20	OLED near5 TFT
<b>22</b>	0	OLED and ((n+m) near5 subframes)
<b>23</b>	0	OLED and TFT and erase
<b>24</b>	0	OLED and TFT and eras\$%
<b>25</b>	1	OLED and (erasi\$5 near5 TFT)
<b>26</b>	6	("5247190"   "5399502"   "5990629"   "6246180"   "6292183"   "6335716").PN.
<b>27</b>	1	OLED and (erasi\$5 with TFT)
<b>28</b>	1	OLED and (erasi\$5 same TFT)
<b>29</b>	0	LED and (erasi\$5 same TFT)
<b>30</b>	6	EL and (erasi\$5 same TFT)
<b>31</b>	4	EL and (erasi\$5 with TFT)

	<b>DBs</b>
<b>1</b>	US-PGPUB; USPAT
<b>2</b>	US-PGPUB; USPAT
<b>3</b>	US-PGPUB; USPAT
<b>4</b>	EPO; JPO; DERWENT; IBM_TDB
<b>5</b>	EPO; JPO; DERWENT; IBM_TDB
<b>6</b>	USPAT
<b>7</b>	USPAT
<b>8</b>	USPAT
<b>9</b>	USPAT
<b>10</b>	USPAT
<b>11</b>	EPO; JPO; DERWENT; IBM_TDB
<b>12</b>	US-PGPUB; USPAT
<b>13</b>	USPAT
<b>14</b>	USPAT
<b>15</b>	EPO; JPO; DERWENT; IBM_TDB
<b>16</b>	USPAT
<b>17</b>	EPO; JPO; DERWENT; IBM_TDB
<b>18</b>	USPAT
<b>19</b>	USPAT
<b>20</b>	USPAT
<b>21</b>	USPAT
<b>22</b>	US-PGPUB; USPAT
<b>23</b>	USPAT
<b>24</b>	USPAT
<b>25</b>	USPAT
<b>26</b>	USPAT
<b>27</b>	USPAT
<b>28</b>	USPAT
<b>29</b>	USPAT
<b>30</b>	USPAT
<b>31</b>	USPAT

	Hits	Search Text
<b>32</b>	2	EL and (erasi\$5 same TFT)
<b>33</b>	10	(EL OLED LED plasma)and (erasi\$5 same TFT)
<b>34</b>	6	(EL OLED LED)and (erasi\$5 same TFT)
<b>35</b>	0	((EL OLED LED)and (erasi\$5 same TFT) ) not ((EL OLED LED plasma)and (erasi\$5 same TFT) )
<b>36</b>	4	((EL OLED LED plasma)and (erasi\$5 same TFT) ) not ((EL OLED LED)and (erasi\$5 same TFT) )
<b>37</b>	1	"6373454".pn.
<b>38</b>	1	"6373454".URPN.
<b>39</b>	5	("5302966"   "5652600"   "6034659"   "6091203"   "6229506").PN.
<b>40</b>	1	"5302966".pn.
<b>41</b>	34	"5302966".URPN.
<b>42</b>	156	EL and (erasi\$5 same line)
<b>43</b>	2	EL with (erasi\$5 adj2 line)
<b>44</b>	13	EL and (erasi\$5 adj2 line)
<b>45</b>	13	EL and (erasi\$5 same line)
<b>46</b>	8	EL with (erasi\$5 near5 line)
<b>47</b>	1	"6040819".pn.
<b>48</b>	3	"6040819".URPN.
<b>49</b>	3	("4827255"   "5479188"   "5539432").PN.
<b>50</b>	9096	TFT and (crystalline adj3 semiconductor near5 film) and (gate adj3 insulating adj3 film) and (gate adj3 electrodes) and (channel adj3 regions)l and (impurity near3 regions)
<b>51</b>	9096	TFT and (crystalline adj3 semiconductor near5 film) and (gate adj3 insulating adj3 film) and (gate adj3 electrodes) and (channel adj3 regions)l and (impurity near3 regions)
<b>52</b>	8391	TFT and (crystalline adj3 semiconductor near5 film) same (gate adj3 insulating adj3 film) same (gate adj3 electrodes) same (channel adj3 regions)l and (impurity near3 regions)
<b>53</b>	8358	TFT same (crystalline adj3 semiconductor near5 film) same (gate adj3 insulating adj3 film) same (gate adj3 electrodes) same (channel adj3 regions)l and (impurity near3 regions)

	<b>DBs</b>
<b>32</b>	EPO; JPO; DERWENT; IBM_TDB
<b>33</b>	USPAT
<b>34</b>	USPAT
<b>35</b>	USPAT
<b>36</b>	USPAT
<b>37</b>	USPAT
<b>38</b>	USPAT
<b>39</b>	USPAT
<b>40</b>	USPAT
<b>41</b>	USPAT
<b>42</b>	USPAT
<b>43</b>	USPAT
<b>44</b>	USPAT
<b>45</b>	EPO; JPO; DERWENT; IBM_TDB
<b>46</b>	USPAT
<b>47</b>	US-PGPUB; USPAT
<b>48</b>	USPAT
<b>49</b>	USPAT
<b>50</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>51</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>52</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>53</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	<b>Hits</b>	<b>Search Text</b>
<b>54</b>	8349	TFT with (crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film) with (gate adj3 electrodes) with (channel adj3 regions)l and (impurity near3 regions)
<b>55</b>	5690	TFT with (crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film) with (gate adj3 electrodes) with (channel adj3 regions)l and (impurity near3 regions)
<b>56</b>	230	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) near5 (gate adj3 electrodes) with (channel adj3 regions)l with (impurity near3 regions)
<b>57</b>	113	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) near5 (gate adj3 electrodes) near7 (channel adj3 regions)l near7 (impurity near3 regions)
<b>58</b>	0	TFT near8 ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) near5 (gate adj3 electrodes) near7 (channel adj3 regions)l near7 ((impurity near3 regions) adj4 (crystalline adj3 semiconductor near5 film) adj4 (channel adj3 regions))
<b>59</b>	0	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) near5 (gate adj3 electrodes) near7 (channel adj3 regions)l near7 ((impurity near3 regions) adj4 (crystalline adj3 semiconductor near5 film) adj4 (channel adj3 regions))
<b>60</b>	0	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) near5 (gate adj3 electrodes) near7 (channel adj3 regions)l with ((impurity near3 regions) adj4 (crystalline adj3 semiconductor near5 film) adj4 (channel adj3 regions))
<b>61</b>	0	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) near7 (channel adj3 regions)l with ((impurity near3 regions) adj4 (crystalline adj3 semiconductor near5 film) adj4 (channel adj3 regions))

	<b>DBs</b>
<b>54</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>55</b>	USPAT
<b>56</b>	USPAT
<b>57</b>	USPAT
<b>58</b>	USPAT
<b>59</b>	USPAT
<b>60</b>	USPAT
<b>61</b>	USPAT

	<b>Hits</b>	<b>Search Text</b>
<b>62</b>	0	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) near7 (channel adj3 regions)I with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions))
<b>63</b>	113	TFT near8 ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) near5 (gate adj3 electrodes) near7 (channel adj3 regions)I near7 (impurity near3 regions)
<b>64</b>	2	TFT with ((crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) with (channel adj3 regions)I with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions))
<b>65</b>	6	TFT with ((crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) with (channel adj3 regions)I with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions))
<b>66</b>	38	TFT and ((crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) with (channel adj3 regions)I with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions))
<b>67</b>	38	TFT and ((crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) with (channel adj3 regions)I with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions)) and ((impurity adj3 region) near3 (pair near4 (impurity adj3 region)))

	<b>DBs</b>
<b>62</b>	USPAT
<b>63</b>	USPAT
<b>64</b>	USPAT
<b>65</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>66</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>67</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	<b>Hits</b>	<b>Search Text</b>
<b>68</b>	38	TFT and ((crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) with (channel adj3 regions)l with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions)) and ((impurity adj3 region) near3 (pair adj3 (impurity adj3 region)))
<b>69</b>	38	TFT and ((crystalline adj3 semiconductor near5 film) with (gate adj3 insulating adj3 film)) with (gate adj3 electrodes) with (channel adj3 regions)l with ((impurity near3 regions) near5 (crystalline adj3 semiconductor near5 film) near5 (channel adj3 regions)) and ((impurity adj3 region) near3 between near3 (pair adj3 (impurity adj3 region)))
<b>70</b>	191	((impurity adj3 region) near3 between near3 (pair adj3 (impurity adj3 region)))
<b>71</b>	3	((impurity adj3 region) adj between adj (pair adj3 (impurity adj3 region)))
<b>72</b>	16	((impurity adj3 region) adj2 between adj2 (pair adj3 (impurity adj3 region)))
<b>73</b>	4	((impurity adj3 region) adj2 between adj2 (pair adj3 (impurity adj3 region))) and TFT
<b>74</b>	0	((impurity adj3 region) adj2 between adj2 (pair adj3 (impurity adj3 region))) and TFT and ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film))
<b>75</b>	4	((impurity adj3 region) with between with (pair adj3 (impurity adj3 region))) and TFT and ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film))
<b>76</b>	0	"T4773738.pn"
<b>77</b>	2	"4773738".pn.

	<b>DBs</b>
<b>68</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>69</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>70</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>71</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>72</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>73</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>74</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>75</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>76</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>77</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	<b>Hits</b>	<b>Search Text</b>
<b>78</b>	2	"5091722".pn.
<b>79</b>	2	"5200846".pn.
<b>80</b>	2	"5225823".pn.
<b>81</b>	2	"5349366".pn.
<b>82</b>	2	"5414442".pn.
<b>83</b>	2	"5424752".pn.
<b>84</b>	2	"5471225".pn.
<b>85</b>	2	"5479283".pn.
<b>86</b>	2	"5583534".pn.
<b>87</b>	2	"5600169".pn.
<b>88</b>	2	"5642129".pn.
<b>89</b>	2	"5712652".pn.
<b>90</b>	2	"5798746".pn.

	<b>DBs</b>
<b>78</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>79</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>80</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>81</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>82</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>83</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>84</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>85</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>86</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>87</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>88</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>89</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>90</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	<b>Hits</b>	<b>Search Text</b>
<b>91</b>	2	"6034659".pn.
<b>92</b>	2	"6157356".pn.
<b>93</b>	2	"6215466".pn.
<b>94</b>	2	"6452341".pn.
<b>95</b>	2	"6542138".pn.
<b>96</b>	2	"6563480".pn.
<b>97</b>	2	"6778152".pn.
<b>98</b>	2	"6791129".pn.
<b>99</b>	2	"5767828".pn.
<b>100</b>	2	"5969710".pn.
<b>101</b>	2	"5986640".pn.
<b>102</b>	2	"6689492".pn.
<b>103</b>	3	"6617644".pn.

	<b>DBs</b>
<b>91</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>92</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>93</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>94</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>95</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>96</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>97</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>98</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>99</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>100</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>101</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>102</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>103</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	<b>Hits</b>	<b>Search Text</b>
<b>104</b>	2	"6236064".pn.
<b>105</b>	2	"5729308".pn.
<b>106</b>	2	"6184559".pn.
<b>107</b>	2	"6246179".pn.
<b>108</b>	2	"6794675".pn.
<b>109</b>	2	"5412493".pn.
<b>110</b>	663	(345/76).CCLS.
<b>111</b>	395	(345/82).CCLS.
<b>112</b>	543	(345/92).CCLS.
<b>113</b>	985	(345/204).CCLS.
<b>114</b>	209	(345/206).CCLS.
<b>115</b>	583	(345/690).CCLS.
<b>116</b>	54	(345/692).CCLS.
<b>117</b>	0	(pseudo adj4 contours) same (pluraliy adj3 frames)
<b>118</b>	27	(pseudo adj4 contours) same subfields
<b>119</b>	23	(pseudo adj4 contours) with subfields
<b>120</b>	36	EL same (erasi\$5 same line)
<b>121</b>	29	EL same (erasi\$5 with line\$4)
<b>122</b>	119	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) adj5 (gate adj3 electrodes) adj7 (channel adj3 regions)I near7 (impurity near3 regions)
<b>123</b>	54	TFT with ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film)) adj5 (gate adj3 electrodes) adj7 (channel adj3 regions)I adj5 (impurity near3 regions)

	<b>DBs</b>
<b>104</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>105</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>106</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>107</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>108</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>109</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>110</b>	USPAT
<b>111</b>	USPAT
<b>112</b>	USPAT
<b>113</b>	USPAT
<b>114</b>	USPAT
<b>115</b>	USPAT
<b>116</b>	USPAT
<b>117</b>	USPAT
<b>118</b>	EPO; JPO; DERWENT; IBM_TDB
<b>119</b>	EPO; JPO; DERWENT; IBM_TDB
<b>120</b>	USPAT
<b>121</b>	USPAT
<b>122</b>	USPAT
<b>123</b>	USPAT

	<b>Hits</b>	<b>Search Text</b>
<b>124</b>	0	(three adj3 TFT\$4) with EL same (subframe44 subfield\$4)
<b>125</b>	6	(three adj3 TFT\$4) with EL
<b>126</b>	12	(three adj3 TFT\$4) same EL
<b>127</b>	0	(three adj3 TFT\$4) same EL same (subframe44 subfield\$4)
<b>128</b>	0	(three adj3 TFT\$4) and EL same (subframe44 subfield\$4)
<b>129</b>	0	(three adj3 TFT\$4) and EL and (subframe44 subfield\$4)
<b>130</b>	5	((impurity adj3 region) same between same (pair adj3 (impurity adj3 region))) and TFT and ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film))
<b>131</b>	5	((impurity adj3 region) and between same (pair adj3 (impurity adj3 region))) and TFT and ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film))
<b>132</b>	7	((impurity adj3 region) and between and (pair adj3 (impurity adj3 region))) and TFT and ((crystalline adj3 semiconductor near5 film) adj3 (gate adj3 insulating adj3 film))

	<b>DBs</b>
<b>124</b>	USPAT
<b>125</b>	USPAT
<b>126</b>	USPAT
<b>127</b>	USPAT
<b>128</b>	USPAT
<b>129</b>	USPAT
<b>130</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>131</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
<b>132</b>	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB